

# **High-Power NPN Silicon Transistor**

 $\dots$  for use as an output device in complementary audio amplifiers to 100-Watts music power per channel.

- High DC Current Gain
  - $h_{FE} = 25-100$  @  $I_C = 7.5$  A
- Excellent Safe Operating Area
- Complement to the PNP MJ4502

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V <sub>CER</sub>	100	Vdc
Collector–Base Voltage	V <sub>CB</sub>	100	Vdc
Collector–Emitter Voltage	V <sub>CEO</sub>	90	Vdc
Emitter–Base Voltage	V <sub>EB</sub>	4.0	Vdc
Collector Current	I <sub>C</sub>	30	Adc
Base Current	I <sub>B</sub>	7.5	Adc
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	200 1.14	Watts W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +200	°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$\theta_{\sf JC}$	0.875	°C/W

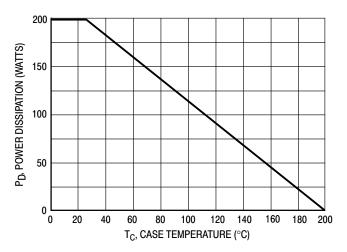


Figure 1. Power-Temperature Derating Curve

# **MJ802**

30 AMPERE
POWER TRANSISTOR
NPN SILICON
100 VOLTS
200 WATTS



CASE 1-07 TO-204AA (TO-3)

## MJ802

# **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS			l	1
Collector–Emitter Breakdown Voltage <sup>(1)</sup> (I <sub>C</sub> = 200 mAdc, R <sub>BE</sub> = 100 Ohms)	BV <sub>CER</sub>	100	_	Vdc
Collector–Emitter Sustaining Voltage <sup>(1)</sup> (I <sub>C</sub> = 200 mAdc)		90	_	Vdc
Collector–Base Cutoff Current $(V_{CB} = 100 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 100 \text{ Vdc}, I_E = 0, T_C = 150^{\circ}\text{C})$	I <sub>CBO</sub>		1.0 5.0	mAdc
Emitter–Base Cutoff Current (V <sub>BE</sub> = 4.0 Vdc, I <sub>C</sub> = 0)	I <sub>EBO</sub>	_	1.0	mAdc
ON CHARACTERISTICS <sup>(1)</sup>				
DC Current Gain <sup>(1)</sup> (I <sub>C</sub> = 7.5 Adc, V <sub>CE</sub> = 2.0 Vdc)	h <sub>FE</sub>	25	100	_
Base–Emitter "On" Voltage (I <sub>C</sub> = 7.5 Adc, V <sub>CE</sub> = 2.0 Vdc)	V <sub>BE(on)</sub>	_	1.3	Vdc
Collector–Emitter Saturation Voltage (I <sub>C</sub> = 7.5 Adc, I <sub>B</sub> = 0.75 Adc)	V <sub>CE(sat)</sub>	_	0.8	Vdc
Base–Emitter Saturation Voltage (I <sub>C</sub> = 7.5 Adc, I <sub>B</sub> = 0.75 Adc)	V <sub>BE(sat)</sub>	_	1.3	Vdc
DYNAMIC CHARACTERISTICS				-
Current Gain — Bandwidth Product (I <sub>C</sub> = 1.0 Adc, V <sub>CE</sub> = 10 Vdc, f = 1.0 MHz)	f <sub>T</sub>	2.0	_	MHz

<sup>(1)</sup> Pulse Test: Pulse Width  $\leq 300 \,\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

## **MJ802**

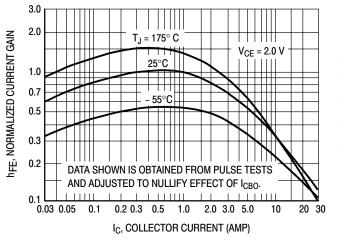


Figure 2. DC Current Gain

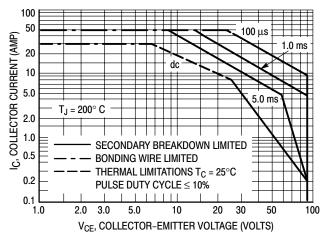


Figure 4. Active Region Safe Operating Area

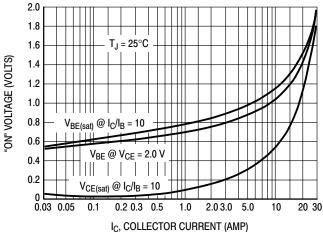


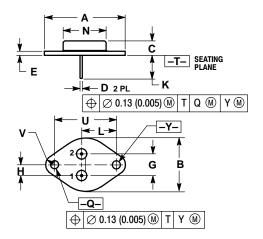
Figure 3. "On" Voltages

The Safe Operating Area Curves indicate  $I_C - V_{CE}$  limits below which the device will not enter secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a catastrophic failure. To insure operation below the maximum  $T_J$ , power temperature derating must be observed for both steady state and pulse power conditions.

#### **MJ802**

#### PACKAGE DIMENSIONS

#### **CASE 1-07** TO-204AA (TO-3) **ISSUE Z**



#### NOTES:

- 1 DIMENSIONING AND TOLERANCING PER ANSI
- 2. CONTROLLING DIMENSION: INCH.
- 3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	1.550 REF		39.37 REF		
В		1.050		26.67	
С	0.250	0.335	6.35	8.51	
D	0.038	0.043	0.97	1.09	
Е	0.055	0.070	1.40	1.77	
G	0.430 BSC		10.92 BSC		
Н	0.215 BSC		5.46 BSC		
K	0.440	0.480	11.18	12.19	
L	0.665 BSC		16.89 BSC		
N		0.830		21.08	
Q	0.151	0.165	3.84	4.19	
U	1.187 BSC		30.15 BSC		
٧	0.131	0.188	3.33	4.77	

STYLE 1: PIN 1. BASE 2. EMITTER CASE: COLLECTOR

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